Sensitive Gate Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed and tested for repetitive peak operation required for CD ignition, fuel ignitors, flash circuits, motor controls and low-power switching applications.

Features

- Blocking Voltage to 600 V
- High Surge Current 15 A
- Very Low Forward "On" Voltage at High Current
- Low-Cost Surface Mount SOT-223 Package
- These are Pb–Free Devices

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

| Rating | Symbol | Value | Unit |
|---|---------------------------------------|------------------|------------------|
| $\begin{tabular}{lllllllllllllllllllllllllllllllllll$ | V _{DRM,} V _{RRM} | 50 400 600 | V |
| On-State Current RMS (180° Conduction Angles, T _C = 80°C) | I _{T(RMS)} | 1.5 | A |
| Peak Non-repetitive Surge Current, @T _A = 25°C, (1/2 Cycle, Sine Wave, 60 Hz) | I _{TSM} | 15 | A |
| Circuit Fusing Considerations (t = 8.3 ms) | l ² t | 0.9 | A ² s |
| Forward Peak Gate Power (Pulse Width \leq 1.0 μ sec, T _A = 25°C) | P _{GM} | 0.5 | W |
| Forward Average Gate Power (t = 8.3 msec, $T_A = 25^{\circ}C$) | P _{G(AV)} | 0.1 | W |
| Forward Peak Gate Current (Pulse Width \leq 1.0 μ s, T _A = 25°C) | I _{FGM} | 0.2 | A |
| Reverse Peak Gate Voltage (Pulse Width \leq 1.0 µs, T _A = 25°C) | V _{RGM} | 5.0 | V |
| Operating Junction Temperature Range @ Rated V _{RRM} and V _{DRM} | ТJ | -40 to +110 | °C |
| Storage Temperature Range | T _{stg} | –40 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

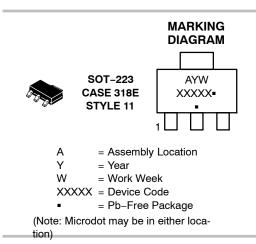


ON Semiconductor®

http://onsemi.com

SCRs 1.5 AMPERES RMS 400 thru 600 VOLTS





| PIN ASSIGNMENT | | |
|----------------|--|--|
| K (Cathode) | | |
| A (Anode) | | |
| G (Gate) | | |
| A (Anode) | | |
| | | |

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------|----------------------|-----------------------|
| NYC222STT1G | SOT-223 (Pb-Free) | 1000 /Tape & Reel |
| NYC226STT1G | SOT–223 (Pb–Free) | 1000 /Tape & Reel |
| NYC228STT1G | SOT-223 (Pb-Free) | 1000 /Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Semiconductor Components Industries, LLC, 2008 July, 2008 – Rev. 0

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction-to-Ambient PCB Mounted | $R_{\theta JA}$ | 156 | °C/W |
| Thermal Resistance, Junction-to-Tab Measured on MT2 Tab Adjacent to Epoxy | $R_{\theta JT}$ | 25 | °C/W |
| Maximum Device Temperature for Soldering Purposes for 10 Secs Maximum | TL | 260 | °C |

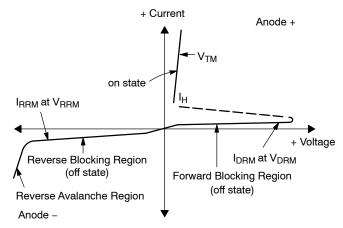
ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted.)

| Characteristic | | Symbol | Min | Тур | Max | Unit |
|--|---|-------------------------------------|-----|---------|------------|----------|
| OFF CHARACTERISTICS | | | 1 | | | |
| Peak Repetitive Forward or Reverse Blocking Current (V _{AK} = Rated V _{DRM} /V _{RRM} ; R _{GK} = 1000 Ω) | T _C = 25°C T _C = 110°C | I _{DRM} , I _{RRM} | | | 10 200 | μΑ μΑ |
| ON CHARACTERISTICS | | | | | | |
| Peak Forward On-State Voltage (Note 2) (I _{TM} = 2.2 A Peak) | | V _{TM} | - | 1.2 | 1.7 | V |
| Gate Trigger Current (dc) (Note 3) $(V_{AK} = 7 \text{ Vdc}, R_L = 100 \Omega)$ | $T_C = 25^{\circ}C$ $T_C = -40^{\circ}C$ | I _{GT} | - | 30 - | 200 500 | μΑ |
| Gate Trigger Voltage (dc) (Note 3) $(V_{AK} = 7 \text{ Vdc}, R_L = 100 \Omega)$ | $T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$ | V _{GT} | | | 0.8 1.2 | V |
| Gate Non-Trigger Voltage $(V_{AK} = V_{DRM}, R_L = 100 \Omega)$ | T _C = 110°C | V _{GD} | 0.1 | - | - | V |
| Holding Current $(V_{AK} = 12 \text{ V}, \text{ R}_{GK} = 1000 \Omega)$ Initiating Current = 200 mA | $T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$ | Ι _Η | | 2.0 | 5.0 10 | mA |
| DYNAMIC CHARACTERISTICS | | | | | | |
| Critical Rate of Rise of Off-State Voltage (T _C = 110°C) | | dv/dt | - | 25 | - | V/µs |

2. Pulse Width = 1.0 ms, Duty Cycle \leq 1%. 3. R_{GK} Current not included in measurement.

Voltage Current Characteristic of SCR

| Symbol | Parameter |
|------------------|---|
| V _{DRM} | Peak Repetitive Off State Forward Voltage |
| I _{DRM} | Peak Forward Blocking Current |
| V _{RRM} | Peak Repetitive Off State Reverse Voltage |
| I _{RRM} | Peak Reverse Blocking Current |
| V _{TM} | Peak on State Voltage |
| I _H | Holding Current |



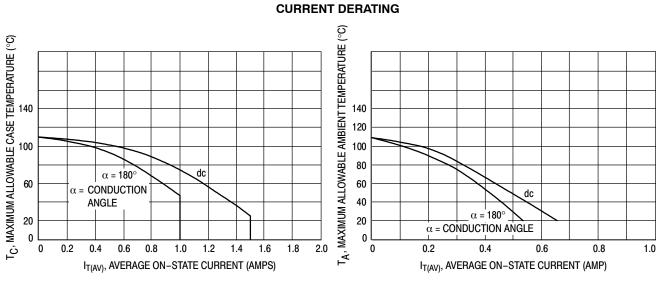
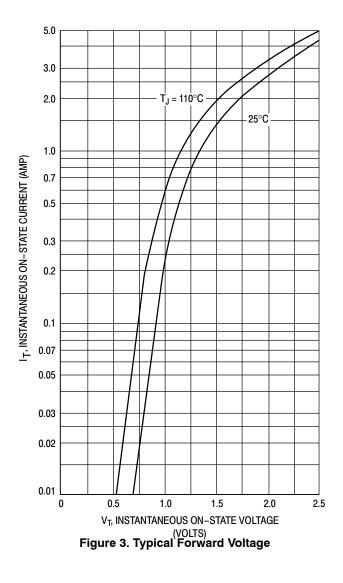
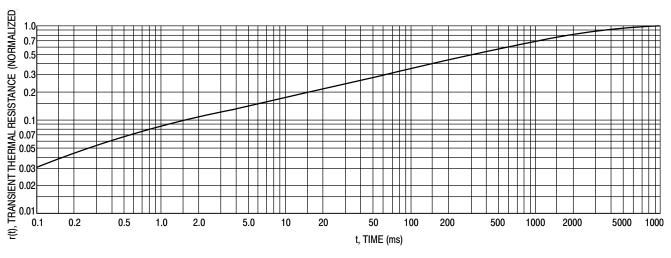




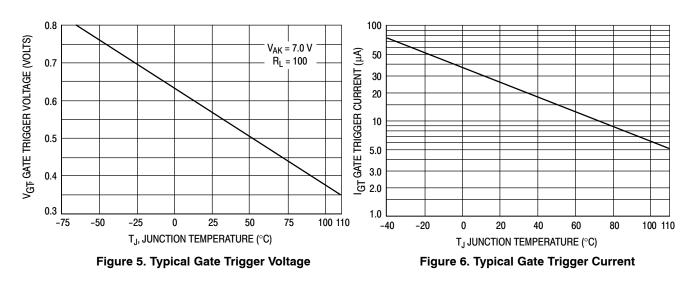
Figure 2. Maximum Ambient Temperature

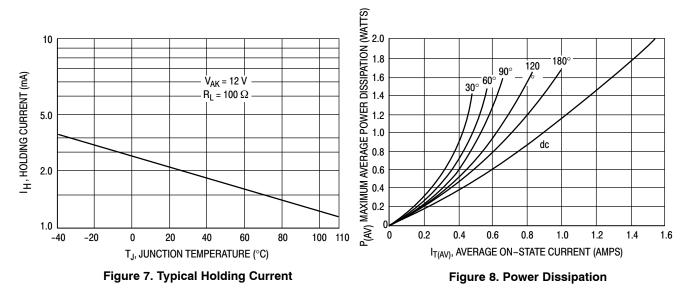






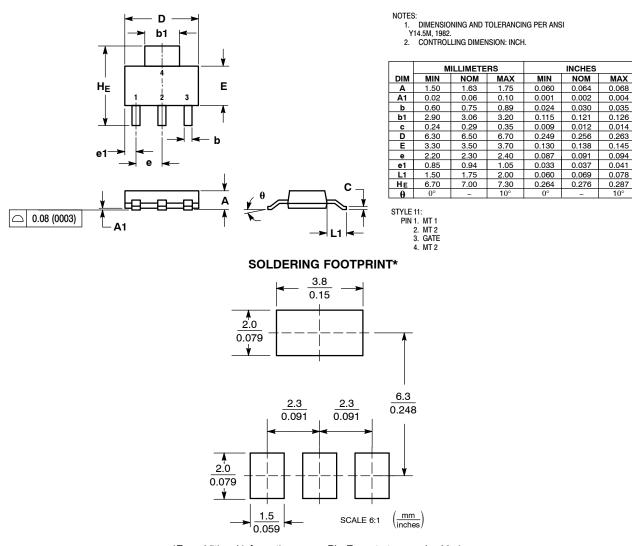






PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUF M



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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